

**2SC5046**

## Ultrahigh-Definition CRT Display Horizontal Deflection Output Applications

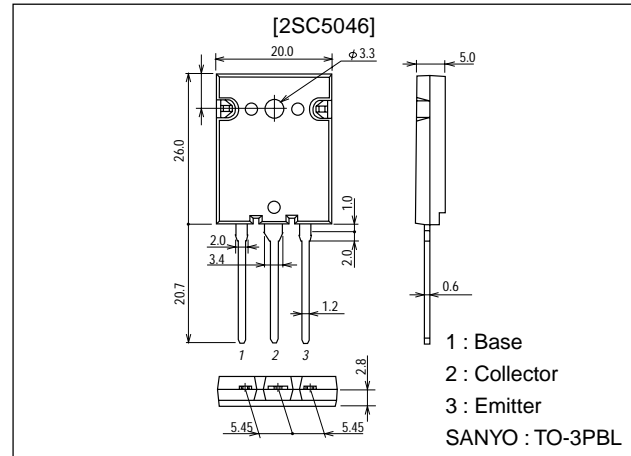
### Features

- High speed ( $t_f=100\text{ns}$  typ).
- High reliability (Adoption of HVP process).
- High breakdown voltage ( $V_{CBO}=1600\text{V}$ ).
- Adoption of MBIT process.

### Package Dimensions

unit:mm

2048B



### Specifications

#### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		1600	V
Collector-to-Emitter Voltage	$V_{CEO}$		800	V
Emitter-to-Base Voltage	$V_{EBO}$		6	V
Collector Current	$I_C$		15	A
Collector Current (Pulse)	$I_{CP}$		35	A
Collector Dissipation	$P_C$		3.5	W
		$T_c=25^\circ\text{C}$	180	W
Junction Temperature	$T_j$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

#### Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=800\text{V}, I_E=0$			10	$\mu\text{A}$
	$I_{CES}$	$V_{CE}=1600\text{V}, R_{BE}=0$			1.0	mA
Collector-to-Emitter Sustain Voltage	$V_{CEO(sus)}$	$I_C=100\text{mA}, I_B=0$	800			V
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=4\text{V}, I_C=0$			1.0	mA
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=12\text{A}, I_B=3\text{A}$			5	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=12\text{A}, I_B=3\text{A}$			1.5	V

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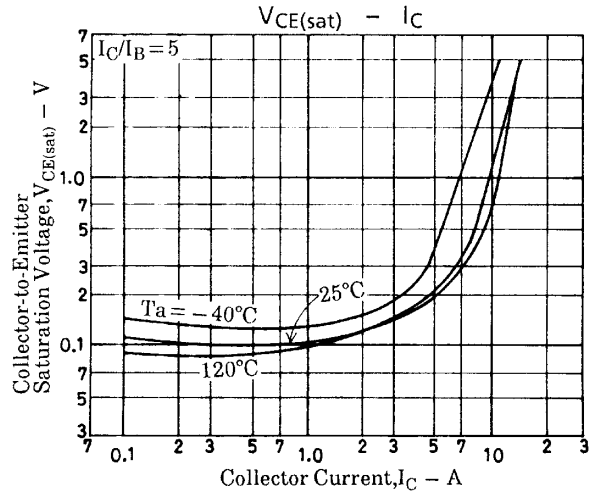
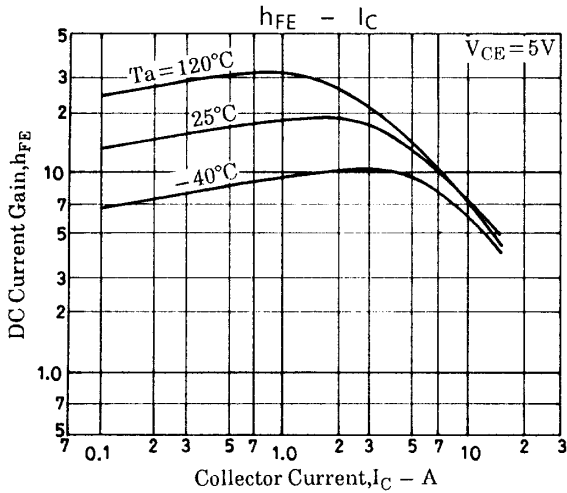
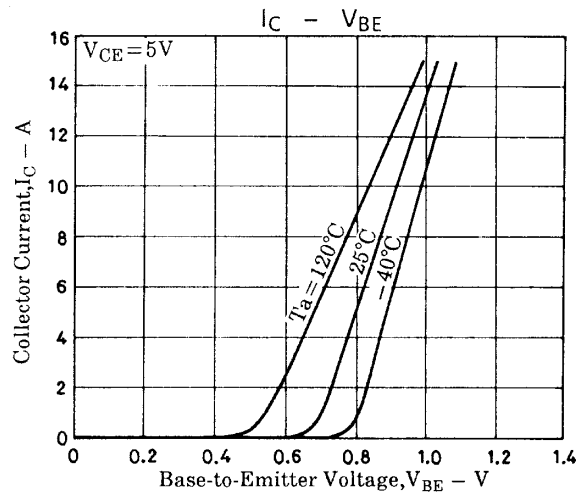
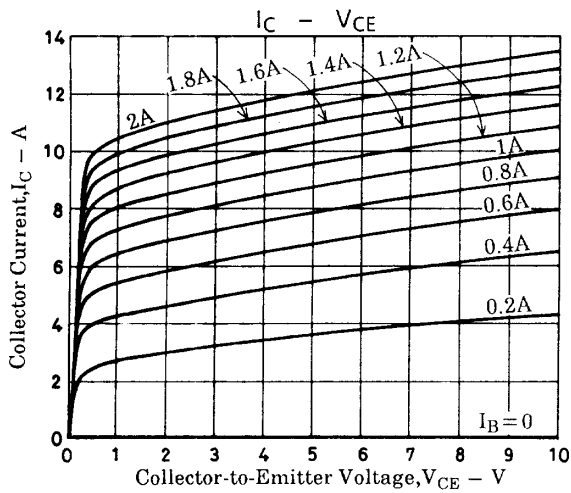
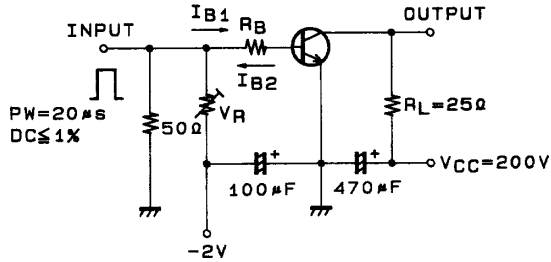
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12599HA (KT)/91294MT (KOTO) B8-0476 No.4784-1/4

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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
DC Current Gain	$h_{FE1}$	$V_{CE}=5V, I_C=1A$	15		25	
	$h_{FE2}$	$V_{CE}=5V, I_C=12A$	4		7	
Storage Time	$t_{stg}$	$I_C=8A, I_{B1}=1.3A, I_{B2}=-4A$			2.0	$\mu s$
Fall Time	$t_f$	$I_C=8A, I_{B1}=1.3A, I_{B2}=-4A$		0.1	0.2	$\mu s$

## Switching Time Test Circuit



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